



Low Voltage, Dual Supply, Low R_{ON} , Quad SPST Analog Switches

DESCRIPTION

The DG9424, DG9425, DG9426 are low voltage precision monolithic quad single-pole-single-throw analog switches.

Using BiCMOS wafer fabrication technology allows the DG9424, DG9425, DG9426 to operate on single and dual supplies. Single supply voltage ranges from 3 V to 12 V while dual supply operation is recommended with ± 3 V to ± 6 V.

Combining high speed (t_{ON} : 42 ns), flat $R_{DS(on)}$ over the analog signal range (Ω), minimal insertion loss (-3 dB at 190 MHz), and excellent crosstalk and off-isolation performance, the DG9424, DG9425, DG9426 are ideally suited for audio and video signal switching.

The DG9424 and DG9425 respond to opposite control logic as shown in the truth table. The DG9426 has two normally open and two normally closed switches.

FEATURES

- 2.7 V thru 12 V single supply or ± 3 thru ± 6 dual supply
- On-resistance - $R_{DS(on)}$: 1.7 Ω
- Fast switching - t_{ON} : 42 ns
- t_{OFF} : 28 ns
- TTL, CMOS compatible
- Low leakage: 0.2 nA
- 2000 V ESD protection

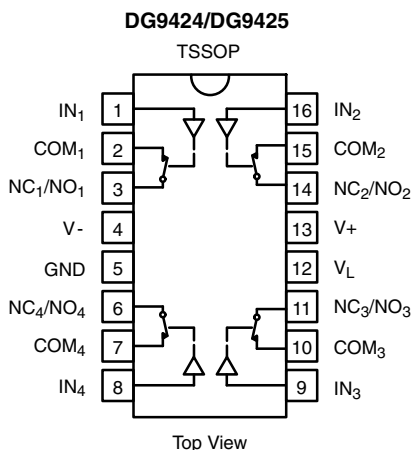
BENEFITS

- Widest dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing

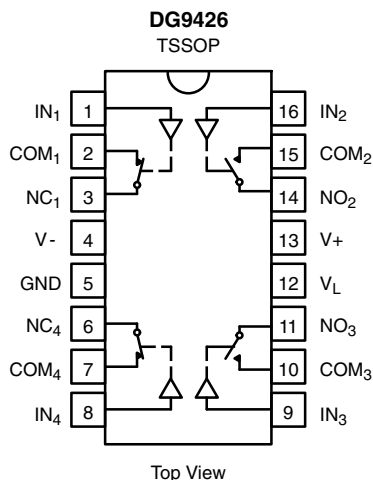
APPLICATIONS

- Automatic test equipment
- Data acquisition systems
- Communication systems
- ADC systems
- xDSL and PBX / PABX
- Audio signal routing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE		
LOGIC	DG9424	DG9425
0	OFF	ON
1	ON	OFF

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

TRUTH TABLE

LOGIC	SW ₁ , SW ₄	SW ₂ , SW ₃
0	ON	OFF
1	OFF	ON

ORDERING INFORMATION

TEMP. RANGE	PACKAGE	PART NUMBER
-40 °C to +85 °C	16-Pin TSSOP	DG9424DQ-T1-E3
		DG9425DQ-T1-E3
		DG9426DQ-T1-E3

ABSOLUTE MAXIMUM RATINGS

PARAMETER	LIMIT	UNIT
V ₊ to V ₋	-0.3 to +13	V
GND to V ₋	7	
V _L	(GND - 0.3) to (V ₊) + 0.3	
IN, COM, NC, NO ^a	(V ₋) - 0.3 to (V ₊) + 0.3	
Continuous Current (NO, NC, COM Pins)	100	mA
Peak Current, S or D (Pulsed 1 ms, 10 % Duty Cycle)	200	
Storage Temperature	-65 to +150	°C
Power Dissipation (Package) ^b	16-Pin TSSOP ^c	mW
Thermal Resistance ^b		°C/W

Notes

- Signals on NC, NO, COM or IN exceeding V₊ or V₋ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC board.
- Derate 7 mW/°C above 25 °C.



SPECIFICATIONS ^a Single Supply 12 V								
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 12 V, V ₋ = 0 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT	
				MIN. ^d	TYP. ^c	MAX. ^d		
Analog Switch								
Analog Signal Range ^e	V _{ANALOG}		Full	0	-	12	V	
On-Resistance	R _{ON}	V ₊ = 10.8 V, V ₋ = 0 V I _{NO} , I _{NC} = 50 mA, V _{COM} = 2 V / 9 V	Room	-	1.8	3	Ω	
			Full	-	-	4		
Digital Control								
Input Current	I _{INL} or I _{INH}		Full	-1	0.01	1	μA	
Dynamic Characteristics								
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _{NO} , V _{NC} = 5 V, see fig. 2	Room	-	42	57	ns	
			Full	-	-	65		
Turn-Off Time ^e	t _{OFF}		Room	-	28	42		
			Full	-	-	44		
Break-Before-Make Time Delay ^e	t _D	DG9426 only, V _{NO} , V _{NC} = 5 V R _L = 300 Ω, C _L = 35 pF	Room	2	-	-		
Charge Injection ^e	Q _{INJ}	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	-	38	-	pC	
Off-Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF f = 1 MHz	Room	-	-56	-	dB	
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	-	-77	-		
NO, NC Off Capacitance ^e	C _{NO(off)}	f = 1 MHz	Room	-	49	-	pF	
	C _{NC(off)}							
COM Off Capacitance ^e	C _{COM(off)}		Room	-	37	-		
Channel On Capacitance ^e	C _{COM(on)}		Room	-	89	-		
Power Supplies								
Positive Supply Current	I ₊	V _{IN} = 0 or V _L	Room	-	0.02	1	μA	
			Full	-	-	5		
Negative Supply Current	I ₋		Room	-1	-0.002	-		
			Full	-5	-	-		
Logic Supply Current	I _L		Room	-	0.002	1		
			Full	-	-	5		
Ground Current	I _{GND}		Room	-1	-0.002	-		
			Full	-5	-	-		



SPECIFICATIONS ^a Dual Supply ± 5 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 5 V, V ₋ = 5 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^d	TYP. ^c	MAX. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	-5		5	V
On-Resistance	R _{ON}	V ₊ = 4.5 V, V ₋ = -4.5 V I _{NO} , I _{NC} = 50 mA, V _{NO} , V _{COM} = $\pm$ 3.5 V	Room	-	2	3.3	Ω
			Full	-	-	4.3	
Switch Off Leakage Current	I _{NO(off)}	V ₊ = 5.5 V, V ₋ = -5.5 V V _{COM} = $\pm$ 4.5 V, V _{NO} , V _{NC} = $\pm$ 4.5 V	Room	-1	-	1	nA
	I _{NC(off)}		Full	-10	-	10	
	I _{COM(off)}		Room	-1	-	1	
			Full	-10	-	10	
Channel On Leakage Current	I _{COM(on)}	V ₊ = 5.5 V, V ₋ = -5.5 V, V _{NO} , V _{NC} = V _{COM} = $\pm$ 4.5 V	Room	-1	-	1	
			Full	-10	-	10	
Digital Control							
Input Current ^a	I _{INL} or I _{INH}		Full	-1	0.05	1	μ A
Dynamic Characteristics							
Turn-On Time ^e	t _{ON}	R _L = 300 Ω , C _L = 35 pF V _{NO} , V _{NC} = $\pm$ 3.5 V, see fig. 2	Room	-	48	67	ns
			Full	-	-	81	
Turn-Off Time ^e	t _{OFF}		Room	-	34	57	
			Full	-	-	67	
Break-Before-Make Time Delay ^e	t _D	DG9426 only, V _{NO} , V _{NC} = 3.5 V R _L = 300 Ω , C _L = 35 pF	Room	2	-	-	
Charge Injection ^e	Q _{INJ}	V _g = 0 V, R _g = 0 Ω , C _L = 1 nF	Room	-	112	-	pC
Off Isolation ^e	OIRR	R _L = 50 Ω , C _L = 5 pF, f = 1 MHz	Room	-	-56	-	dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	-	-82	-	
Source Off Capacitance ^e	C _{NO(off)} C _{NC(off)}	f = 1 MHz	Room	-	38	-	pF
Drain Off Capacitance ^e	C _{COM(off)}		Room	-	38	-	
Channel On Capacitance ^e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Positive Supply Current ^e	I ₊	V _{IN} = 0 or V _L	Room	-	0.03	1	μ A
			Full	-	-	5	
Negative Supply Current ^e	I ₋		Room	-1	-0.002	-	
			Full	-5	-	-	
Logic Supply Current ^e	I _L		Room	-	0.002	1	
			Full	-	-	5	
Ground Current ^e	I _{GND}		Room	-1	-0.002	-	
			Full	-5	-	-	



SPECIFICATIONS ^a Single Supply 5 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 5 V, V ₋ = 0 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^d	TYP. ^c	MAX. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	-	-	5	V
On-Resistance ^e	R _{ON}	V ₊ = 4.5 V, I _{NO} , I _{NC} = 50 mA, V _{COM} = 1 V, 3.5 V	Room	-	3.4	4.8	Ω
			Full	-	-	5.8	
Dynamic Characteristics							
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _{NO} , V _{NC} = 3.5 V, see fig. 2	Room	-	71	86	ns
			Hot	-	-	106	
Turn-Off Time ^e	t _{OFF}		Room	-	37	51	
			Hot	-	-	56	
Break-Before-Make Time Delay ^e	t _D	DG9426 only, V _{NO} , V _{NC} = 3.5 V R _L = 300 Ω, C _L = 35 pF	Room	5	-	-	
Charge Injection ^e	Q _{INJ}	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	-	10	-	pC
Power Supplies							
Positive Supply Current ^e	I ₊	V _{IN} = 0 or V _L	Room	-	0.02	1	μA
			Hot	-	-	5	
Negative Supply Current ^e	I ₋		Room	-1	-0.002	-	
			Hot	-5	-	-	
Logic Supply Current ^e	I _L		Room	-	0.002	1	
			Hot	-	-	5	
Ground Current ^e	I _{GND}		Room	-1	-0.002	-	
			Hot	-5	-	-	

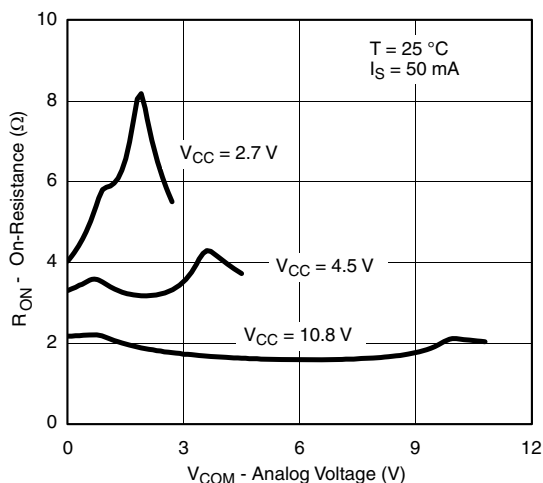
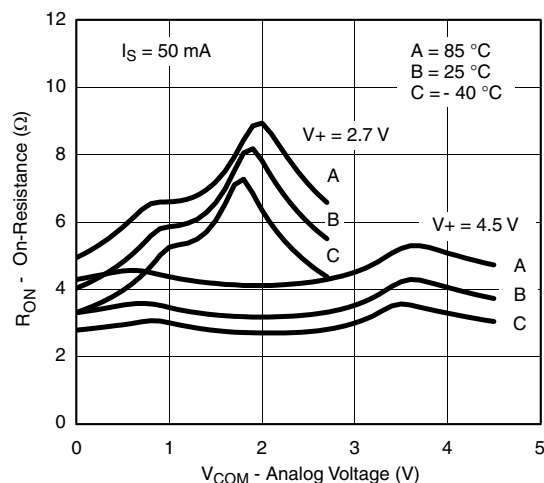
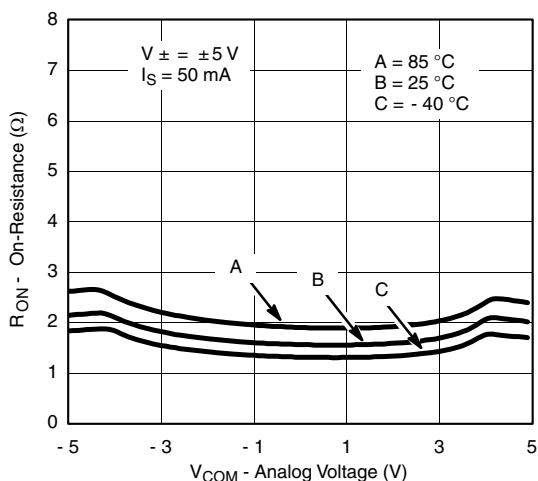
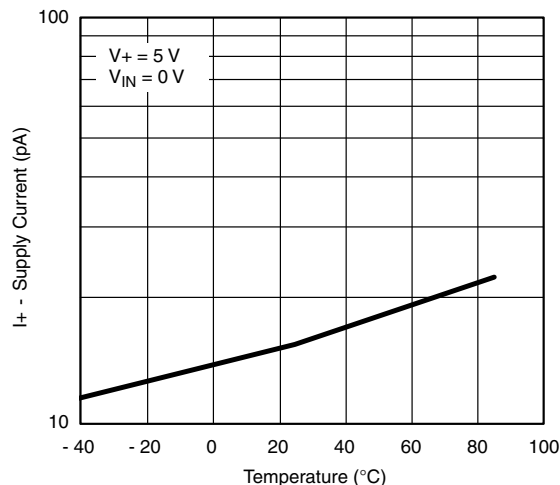
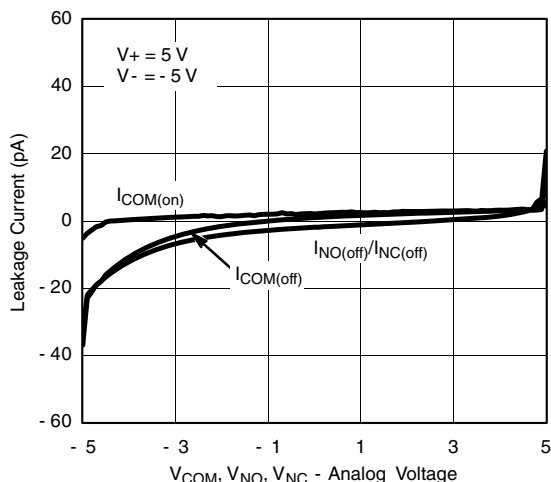
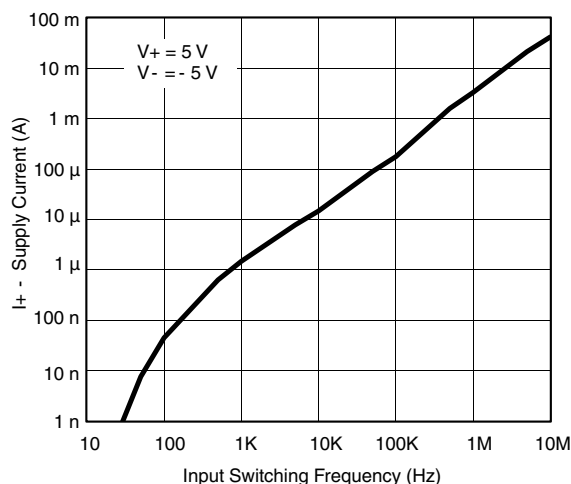


SPECIFICATIONS ^a Single Supply 3 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 3 V, V ₋ = 0 V V _L = 3 V, V _{IN} = 2.4 V, 0.4 V ^f	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^d	TYP. ^c	MAX. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	0	-	3	V
On-Resistance	R _{ON}	V ₊ = 2.7 V, V ₋ = 0 V I _{NO} , I _{NC} = 5 mA, V _{COM} = 0.5 V, 2.2 V	Room	-	8	13.8	Ω
			Full	-	-	15.1	
Switch Off Leakage Current ^a	I _{NO(off)}	V ₊ = 3.3 V, V ₋ = 0 V V _{COM} = 0.3 V, 3 V, V _{NO} , V _{NC} = 3, 0.3 V	Room	-1	-	1	nA
	I _{NC(off)}		Full	-10	-	10	
	I _{COM(off)}		Room	-1	-	1	
			Full	-10	-	10	
Channel On Leakage Current ^a	I _{COM(on)}	V ₊ = 3.3 V, V ₋ = 0 V, V _{NO} , V _{NC} = V _{COM} = 0.3 V, 3 V	Room	-1	-	1	nA
			Full	-10	-	10	
Digital Control ^e							
Input Current	I _{INL} or I _{INH}		Full	-1	0.005	1	μA
Dynamic Characteristics							
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _{NO} , V _{NC} = 1.5 V, see fig. 2	Room	-	140	163	ns
			Full	-	-	193	
Turn-Off Time	t _{OFF}		Room	-	65	80	
			Full	-	-	89	
Break-Before-Make Time Delay	t _D	DG9426 only, V _{NO} , V _{NC} = 1.5 V R _L = 300 Ω, C _L = 35 pF	Room	5			
Charge Injection ^e	Q _{INJ}	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	-	15	-	pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF f = 1 MHz	Room	-	-56	-	dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	-	-80	-	
Source Off Capacitance ^e	C _{NO(off)}	f = 1 MHz	Room	-	53	-	pF
	C _{NC(off)}						
Drain Off Capacitance ^e	C _{COM(off)}		Room	-	42	-	
Channel On Capacitance ^e	C _{COM(on)}		Room	-	92	-	

Notes

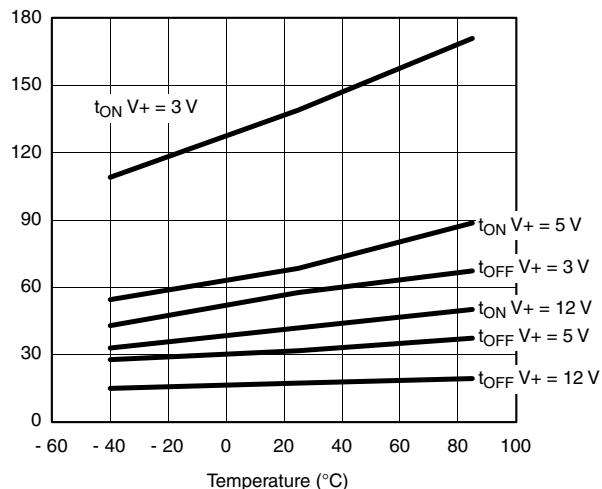
- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test.
b. Room = 25 °C, Full = As determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
e. Guaranteed by design, not subject to production test.
f. V_{IN} = Input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

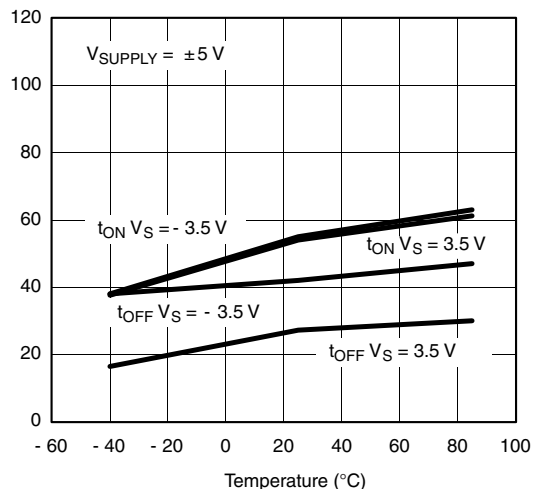
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

 R_{ON} vs. V_{COM} and Supply Voltage

 R_{ON} vs. Analog Voltage and Temperature

 R_{ON} vs. Analog Voltage and Temperature

Supply Current vs. Temperature

Leakage Current vs. Analog Voltage

Switching Current vs. Input Switching Frequency



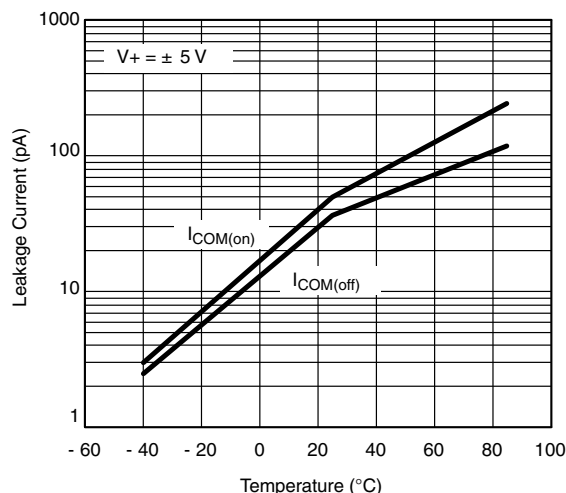
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



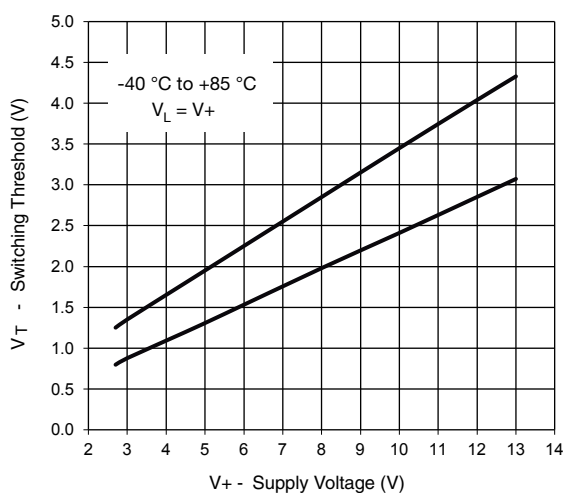
Switching Time vs. Temperature and Single Supply Voltage



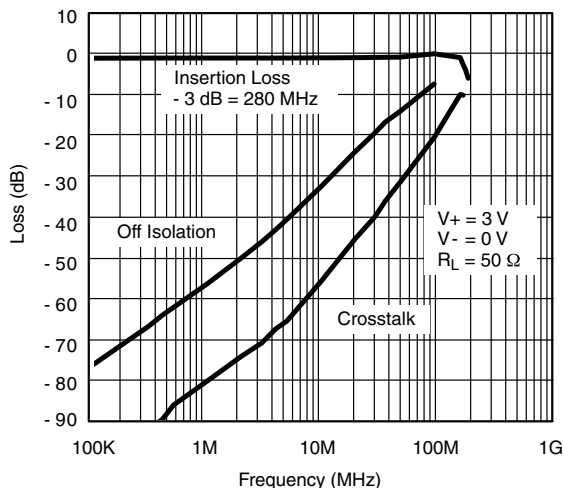
Switching Time vs. Temperature and Dual Supply Voltage



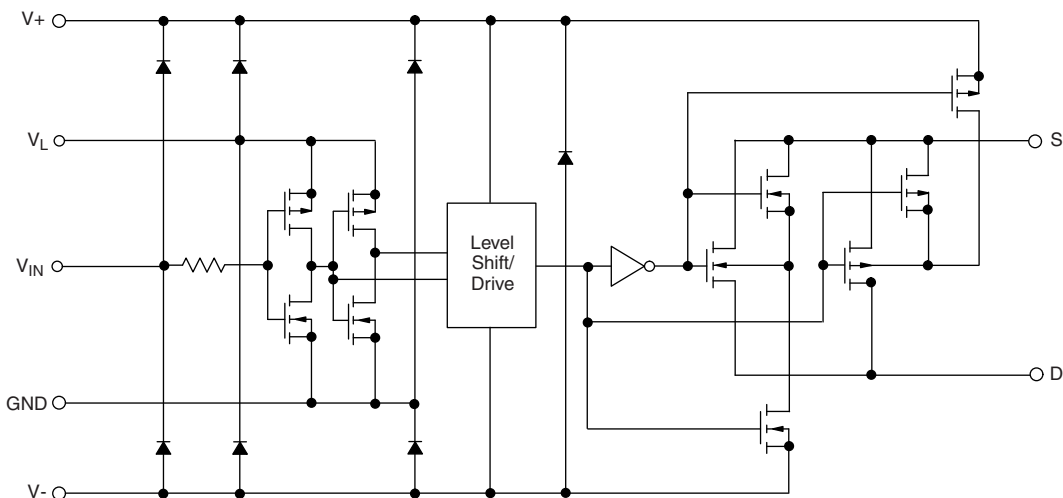
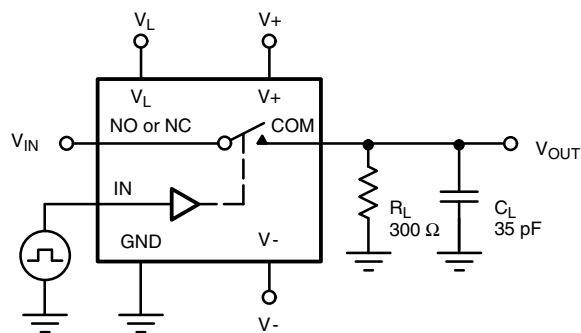
Leakage Current vs. Temperature



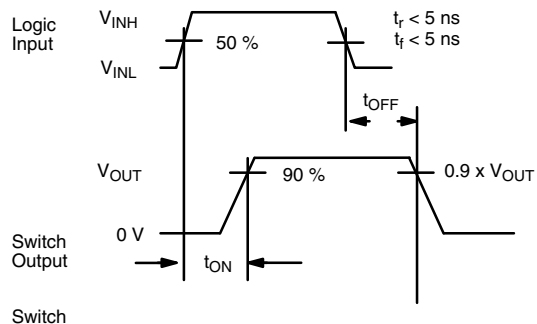
Switching Threshold vs. Supply Voltage



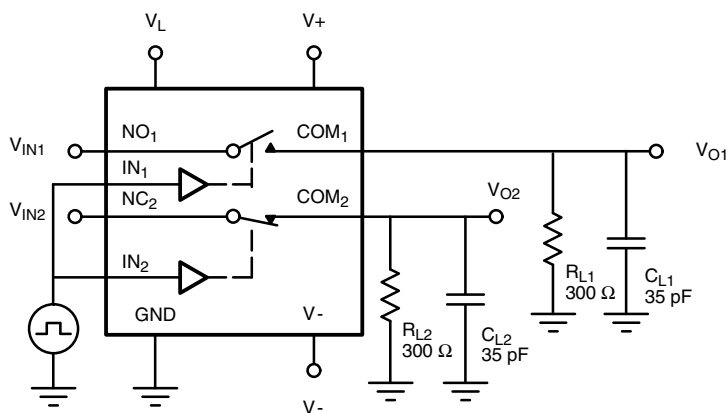
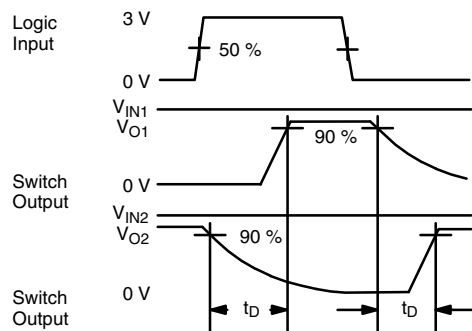
Insertion Loss, Off Isolation and Crosstalk vs. Frequency

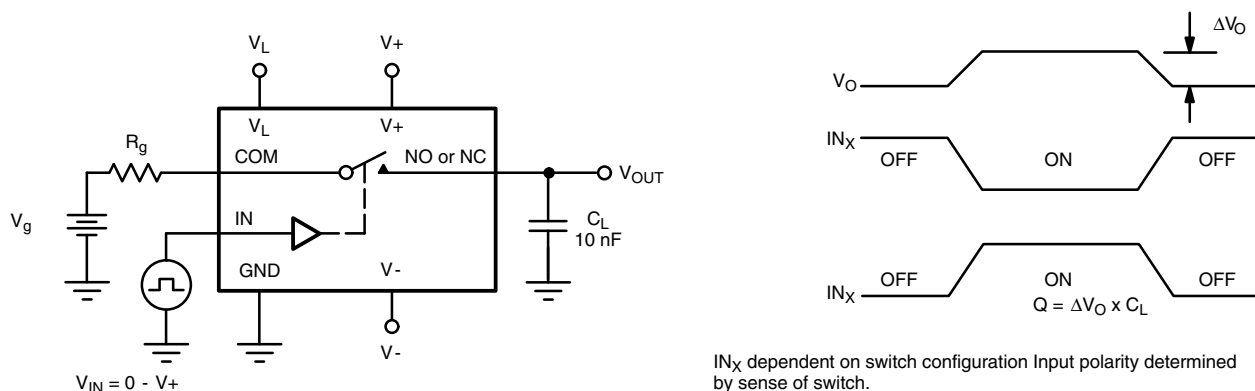
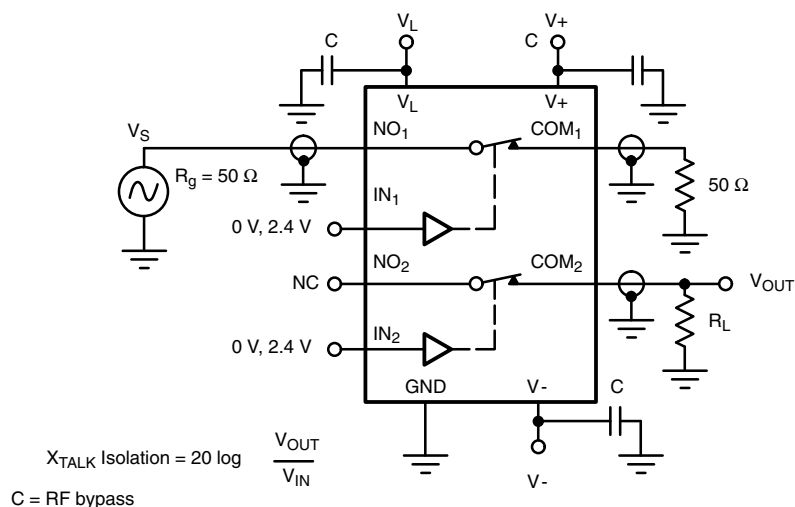
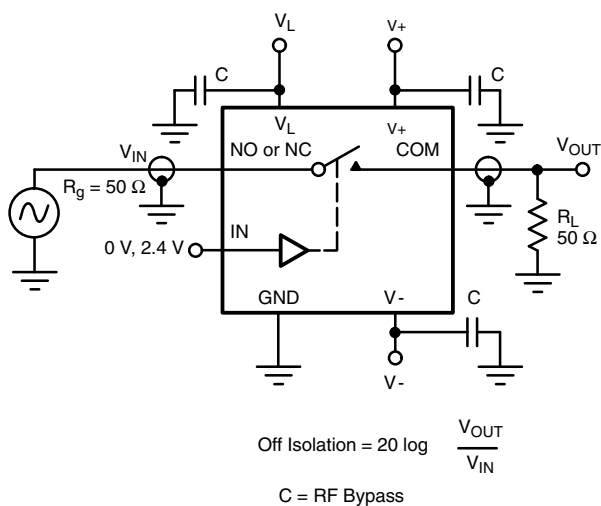
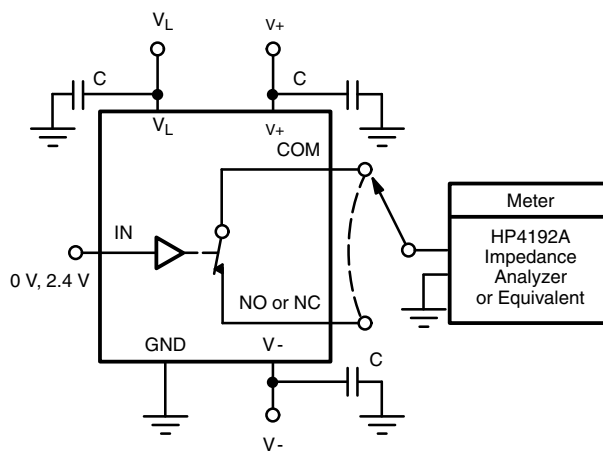
SCHEMATIC DIAGRAM (typical channel)

Fig. 1
TEST CIRCUITS

 C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{IN} \frac{R_L}{R_L + r_{ON}}$$



Note: Logic input waveform is inverted for switches that have the opposite logic sense control

Fig. 2 - Switching Time

 C_L (includes fixture and stray capacitance)

Fig. 3 - Break-Before-Make (DG9426)

TEST CIRCUITS

Fig. 4 - Charge Injection

Fig. 5 - Crosstalk

Fig. 6 - Off-Isolation

Fig. 7 - Source / Drain Capacitances

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TSSOP: 16-LEAD



Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			



RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)



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